

Vishay Telefunken



Silicon NPN Phototransistor

Description

BPW16N is a silicon NPN epitaxial planar phototransistor in a miniature plastic case with flat window. With a lead center to center spacing of 2.54mm and a package width of 2.4mm the devices are easily stackable on PC boards and assembled to arrays of unlimited size.

Due to its waterclear epoxy the device is sensitive to visible and near infrared radiation.

Features

- Miniature T-3/4 flat clear plastic package
- Very wide viewing angle $\phi = \pm 40^{\circ}$
- Suitable for 0.1" (2.54 mm) center to center spac-• ing
- Suitable for visible and near infrared radiation
- Compatible with IR diode CQY36N

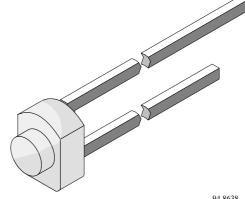
Applications

Detector in electronic control and drive circuits

Absolute Maximum Ratings

 $T_{amb} = 25^{\circ}C$

Test Conditions	Symbol	Value	Unit
	V _{CEO}	V _{CEO} 32	
	V _{ECO}	5	V
	Ι _C	50	mA
$t_p/T = 0.5, t_p \le 10 \text{ ms}$	I _{CM}	100	mA
$T_{amb} \leq 55 \degree C$	P _{tot}	100	mW
	Ti	100	°C
	T _{stg}	-55+100	°C
t ≦ 3 s	T _{sd}	260	°C
	R _{thJA}	450	K/W
	$t_p/T = 0.5, t_p \le 10 \text{ ms}$ $T_{amb} \le 55 \text{ °C}$	$\label{eq:linear_constraint} \begin{array}{c} V_{CEO} \\ V_{ECO} \\ I_C \\ t_p/T = 0.5, t_p \leq 10 \text{ ms} & I_{CM} \\ T_{amb} \leq 55 \ ^\circ C & P_{tot} \\ & T_j \\ T_{stg} \\ t \leq 3 \text{ s} & T_{sd} \end{array}$	$\begin{tabular}{ c c c c c c c c c c c c c c c c c c c$



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Basic Characteristics

 $T_{amb} = 25^{\circ}C$

Parameter	Test Conditions	Symbol	Min	Тур	Max	Unit
Collector Emitter Breakdown Voltage	I _C = 1 mA	V _{(BR)CE}	32			V
Collector Dark Current	V _{CE} = 20 V, E = 0	I _{CEO}		1	200	nA
Collector Emitter Capacitance	V _{CE} = 5 V, f = 1 MHz, E = 0	C _{CEO}		8		pF
Collector Light Current	$E_e = 1 \text{ mW/cm}^2$, $\lambda = 950 \text{ nm}$, $V_{CE} = 5 \text{ V}$	I _{ca}	0.07	0.14		mA
Angle of Half Sensitivity		φ		±40		deg
Wavelength of Peak Sensitivity		λρ		825		nm
Range of Spectral Bandwidth		λ _{0.5}		620960		nm
Collector Emitter Saturation Voltage	$E_e = 1 \text{ mW/cm}^2$, $\lambda = 950 \text{ nm}$, $I_C = 0.01 \text{ mA}$	V _{CEsat}			0.3	V
Turn–On Time	$V_S = 5 V$, $I_C = 5 mA$, $R_L = 100 \Omega$	t _{on}		4.8		μs
Turn–Off Time	$V_S = 5 V$, $I_C = 5 mA$, $R_L = 100 \Omega$	t _{off}		5.0		μs
Cut–Off Frequency	$V_S = 5 V$, $I_C = 5 mA$, $R_L = 100 \Omega$	f _c		120		kHz

Typical Characteristics ($T_{amb} = 25^{\circ}C$ unless otherwise specified)

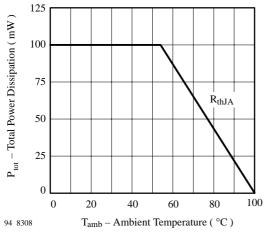


Figure 1. Total Power Dissipation vs. Ambient Temperature

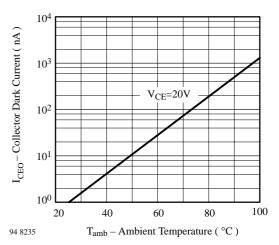
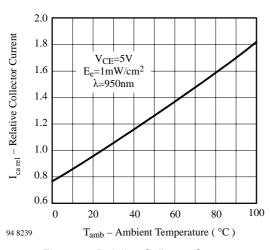


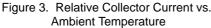
Figure 2. Collector Dark Current vs. Ambient Temperature

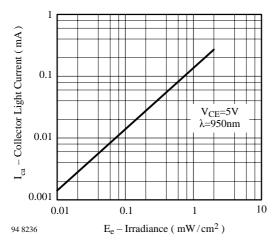


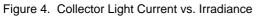
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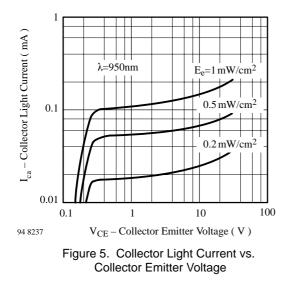
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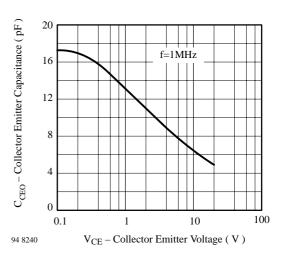


Figure 6. Collector Emitter Capacitance vs. Collector Emitter Voltage

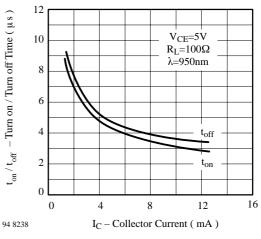
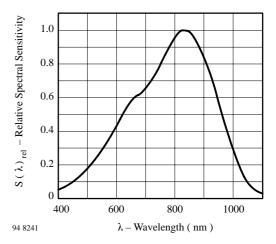


Figure 7. Turn On/Turn Off Time vs. Collector Current

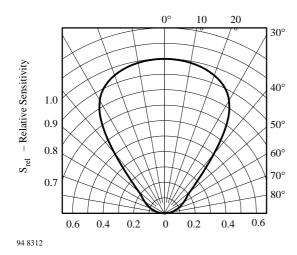




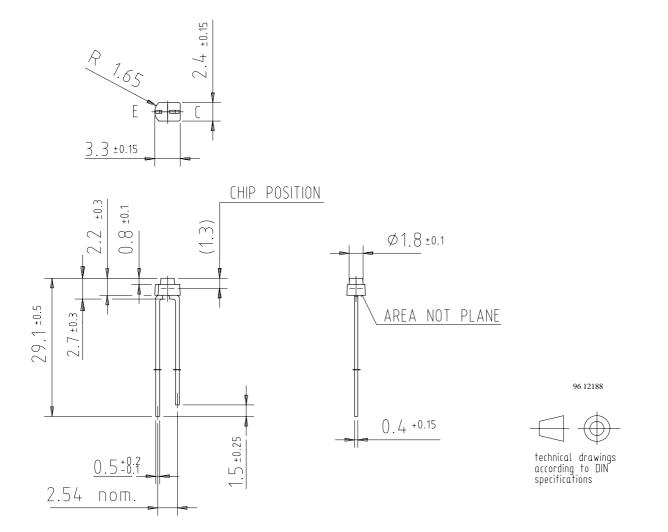
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Ozone Depleting Substances Policy Statement

It is the policy of Vishay Semiconductor GmbH to

- 1. Meet all present and future national and international statutory requirements.
- 2. Regularly and continuously improve the performance of our products, processes, distribution and operating systems with respect to their impact on the health and safety of our employees and the public, as well as their impact on the environment.

It is particular concern to control or eliminate releases of those substances into the atmosphere which are known as ozone depleting substances (ODSs).

The Montreal Protocol (1987) and its London Amendments (1990) intend to severely restrict the use of ODSs and forbid their use within the next ten years. Various national and international initiatives are pressing for an earlier ban on these substances.

Vishay Semiconductor GmbH has been able to use its policy of continuous improvements to eliminate the use of ODSs listed in the following documents.

- 1. Annex A, B and list of transitional substances of the Montreal Protocol and the London Amendments respectively
- 2. Class I and II ozone depleting substances in the Clean Air Act Amendments of 1990 by the Environmental Protection Agency (EPA) in the USA
- 3. Council Decision 88/540/EEC and 91/690/EEC Annex A, B and C (transitional substances) respectively.

Vishay Semiconductor GmbH can certify that our semiconductors are not manufactured with ozone depleting substances and do not contain such substances.

We reserve the right to make changes to improve technical design and may do so without further notice.

Parameters can vary in different applications. All operating parameters must be validated for each customer application by the customer. Should the buyer use Vishay-Telefunken products for any unintended or unauthorized application, the buyer shall indemnify Vishay-Telefunken against all claims, costs, damages, and expenses, arising out of, directly or indirectly, any claim of personal damage, injury or death associated with such unintended or unauthorized use.

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